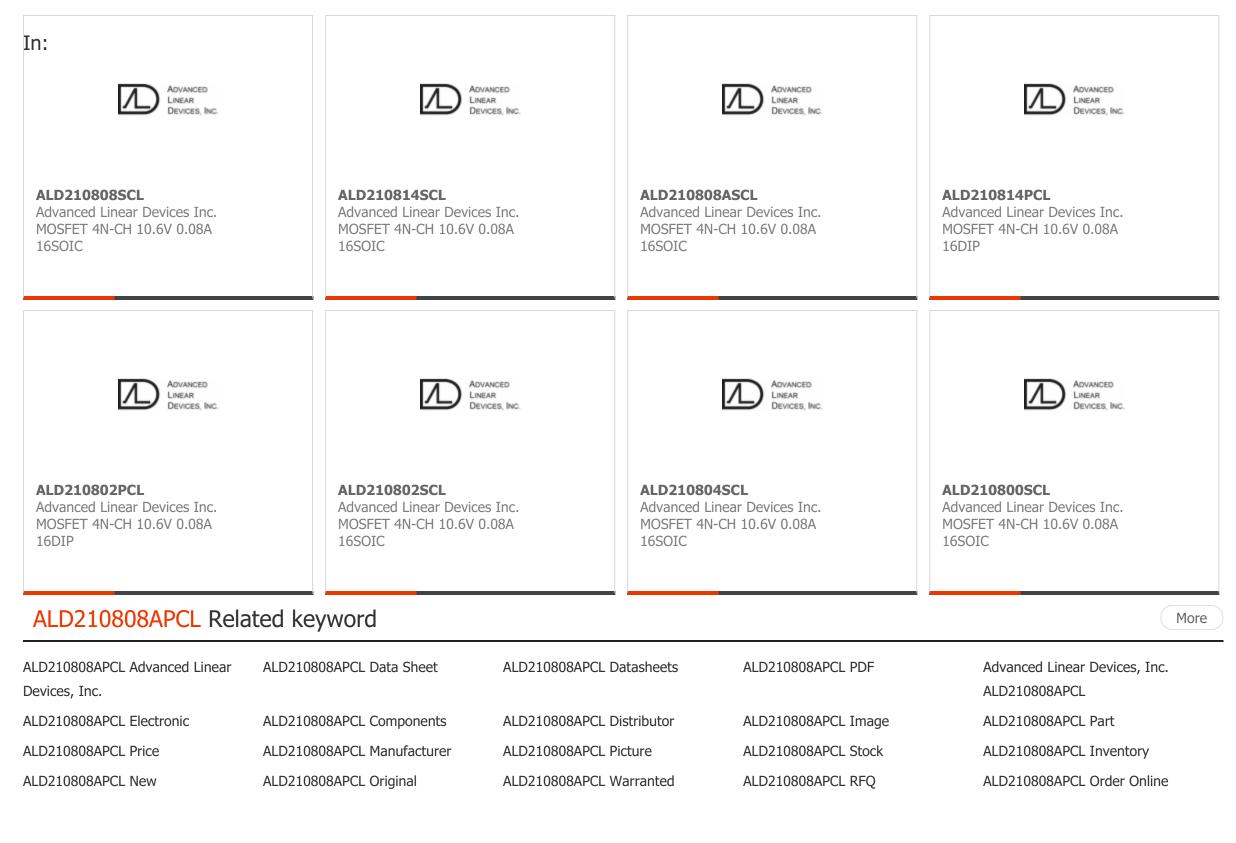


Specifications

Part Number	ALD210808APCL
Manufacturer	Advanced Linear Devices, Inc.
Description	MOSFET 4N-CH 10.6V 0.08A 16DIP
Category	Discrete Semiconductor Products > Transistors - FETs,
Part Status	2508 pcs Stock
Vgs(th) (Max) @ Id	20mV @ 10μA
Supplier Device Package	16-PDIP
Series	EPAD®, Zero Threshold™
Rds On (Max) @ Id, Vgs	-
Power - Max	500mW
Packaging	Tube
Package / Case	16-DIP (0.300", 7.62mm)
Operating Temperature	0°C ~ 70°C (TJ)
Mounting Type	Through Hole
Input Capacitance (Ciss) (Max) @ Vds	-
Gate Charge (Qg) (Max) @ Vgs	-
FET Type	4 N-Channel, Matched Pair
FET Feature	Logic Level Gate
Drain to Source Voltage (Vdss)	10.6V
Current - Continuous Drain (Id) @ 25°C	80mA

You May Be Also Be interested



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